

DF2005S-G thru DF210S-G

"-G" : RoHS Device

REVERSE VOLTAGE - 50 to 1000Volts FORWARD CURRENT - 2.0 Amperes

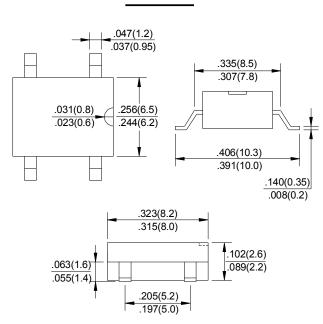
DFS

FEATURES

- Rating to 1000V PRV
- Ideal for printed circuit board
- Low forward voltage drop, high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- The plastic material has UL flammability classification 94V-0

MECHANICAL DATA

- Polarit:As marked on Body
- Weight:0.02 ounces,0.38 grams
- Mounting position: Any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 $^\circ\!\!\!\mathrm{C}$ ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

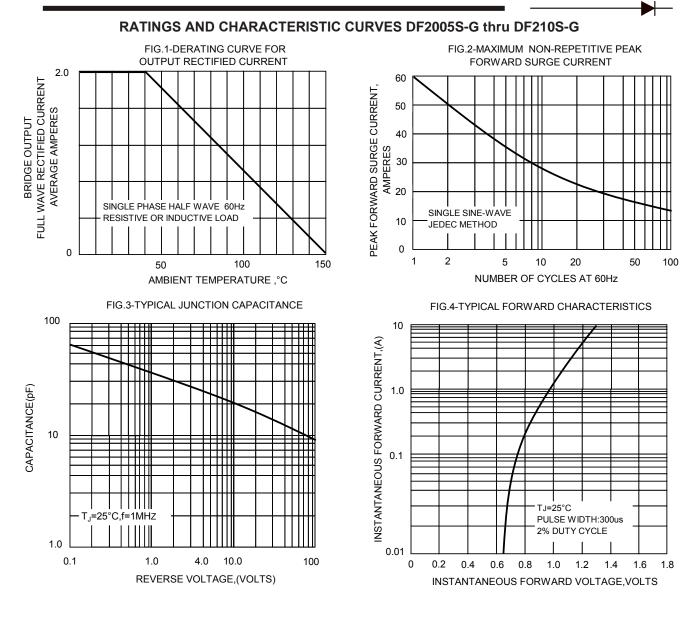
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	DF 2005S	DF 201S	DF 202S	DF 204S	DF 206S	DF 208S	DF 210S	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @Ta=40℃	l(AV)	2.0							А
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC .Method)	IFSM	60							A
Maximum Forward Voltage at 2.0A DC	VF	1.1							V
Maximum DC Reverse Current @TJ=25°C at Rated DC Blocking Voltage @TJ=125°C	lR	10 500							μA
I ² t Rating for Fusing (t<8.3ms)	l ² t	10.4							A ² s
Typical Junction capacitance Per Element(Note1)	CJ	25							pF
Typical Thermal Resistance (Note2)	Reja	40							°C/W
Operating Temperature Range	TJ	-55 to +150							°C
Storage Temperature Range	Tstg	-55 to +150							°C

Note:1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC

2. Thermal resistance from junction to ambient mounted on P.C.B

with 0.5*0.5"(13*13mm) copper pads.



SMD DIODE



